

**ABSTRACT OR SUPPORTING INFORMATION**

**Presentation/Publication Information:**

An invited talk to be given by Deepak Srivastava of the Computational Nanotechnology task at the monthly Silicon Valley Computer Club gathering on 17th March, 1999 at 8, Almandra Lane, Los Altos, CA. A copy of the presentation is attached.

**Acknowledgments:**

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**Abstract:**

An invited talk to review the status of the progress in Nanotechnology, based on publicly available, already presented and/or published material. The copy of the slides are enclosed. No abstract was required or submitted for this presentation.





### Carbon based Nanotechnology- Review

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### Review of Carbon Nanotechnology: in context of Drexler's Molecular Nanotechnology.

- Concept: Feynman's postulate
- Vision: Molecular Assemblers
- Progress in Microtechnology



### Research Focus



Nano-mechanics/materials



Carbon based electronics



BxCxN<sub>x</sub> Nanotubes

#### Nanodevice /Materials Applications



Nanotube-Motor



Nano-lithography



H<sub>2</sub> Storage in nanotubes



### Nanotube - Nanomechanics



- Nanotubes are extremely strong highly elastic nanofibers  
~ high value of Young modulus swnt ~ 1.2 TPa
- Dynamic response of nanotubes to ballistic deformation  
~ axial compression, bending and torsion

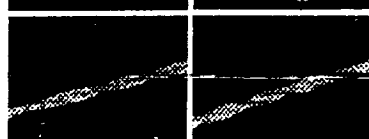
Axial Compression



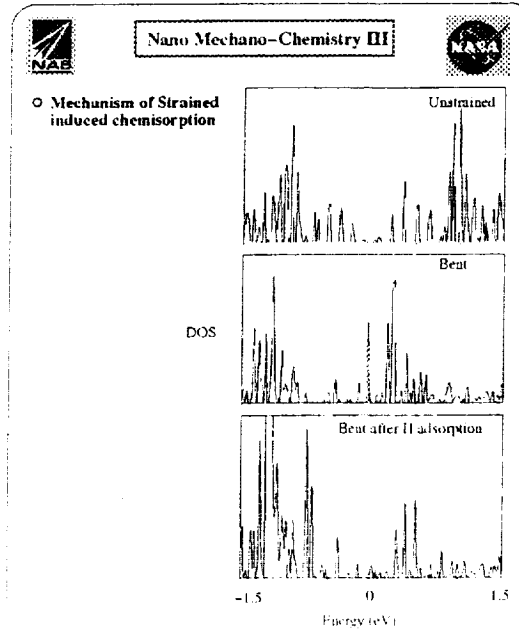
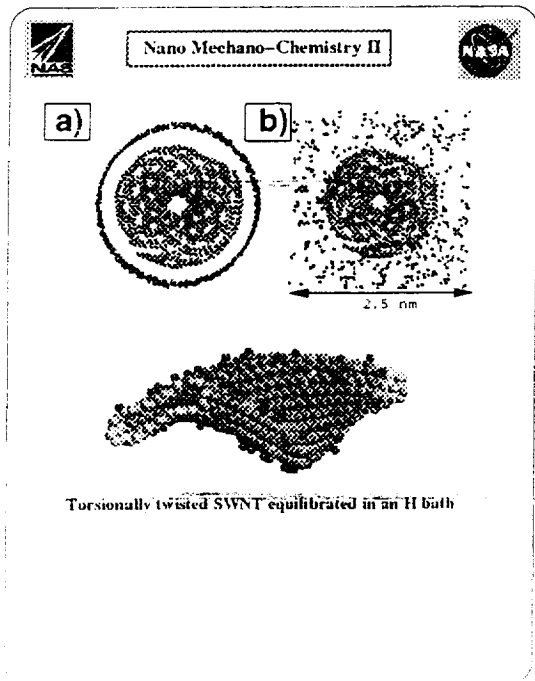
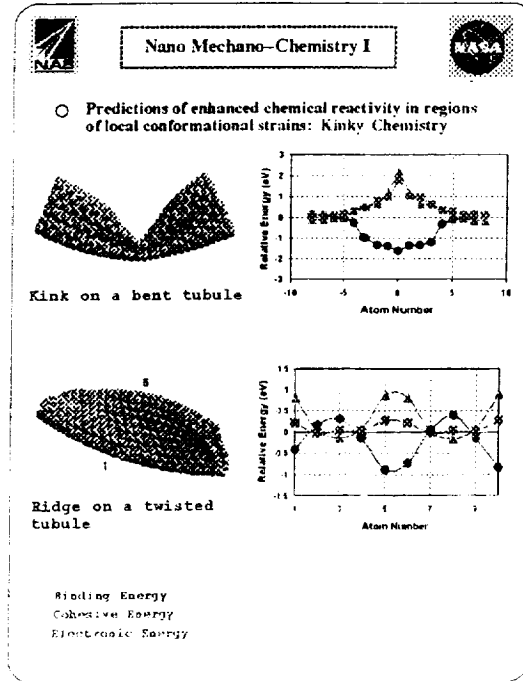
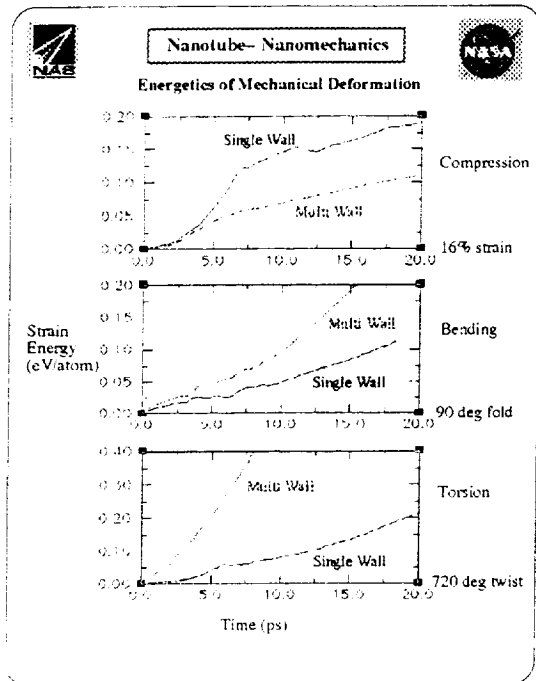
Bending



Torsion



- redistribution of strain
- sharp buckling leading to bond rupture



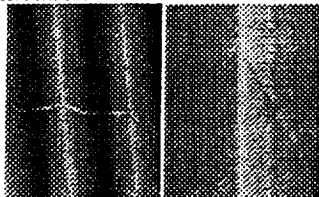


### Nano Mechano-Chemistry III

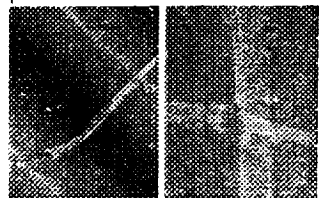


SEM images of MWNTs dispersed on a V-ridge substrate

(a) Before Reaction



(b) Same sample after exposure to nitric acid vapor at room temperature



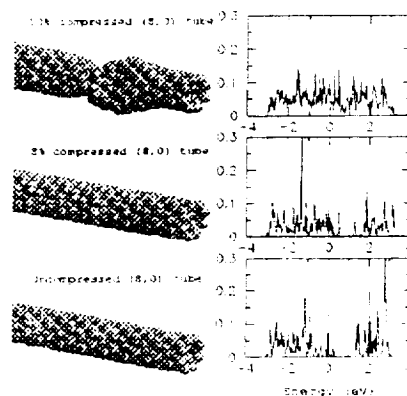
"Predictions of enhanced chemical reactivity in regions of local conformational strains: kinky chemistry," D. Srivastava, J. D. Schaut, D. W. Brenner, K. D. Ausman, M. Feng, and R. Ruoff, submitted, *J. Phys. Chem* (1999)



### Nano Mechano-Electronics I



Mechanical deformations alter the Electronic Characteristics of Nanotubes



Nano mechano-electronics effects are "strongly" dependent on the chiralities

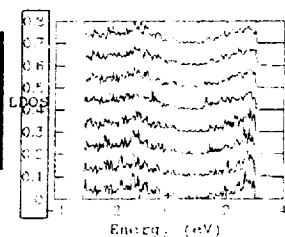
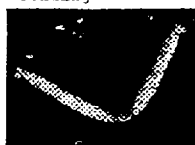


### Nano Mechano-Electronics II

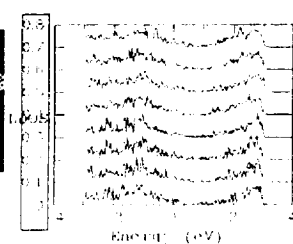


Example: bending and torsion of arm-chair (1,10) nanotube

Bending



Torsion



### Research Focus II Carbon based Electronics



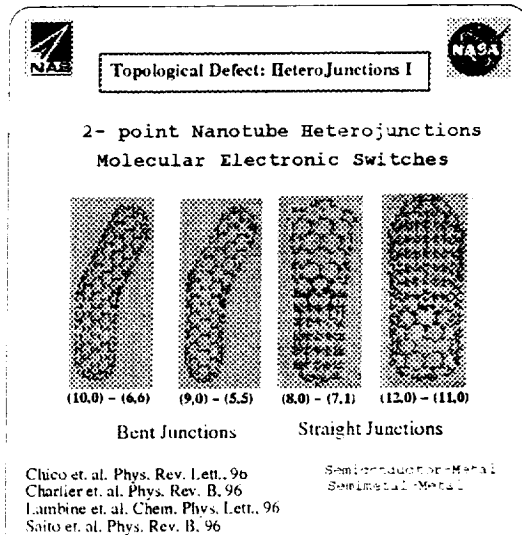
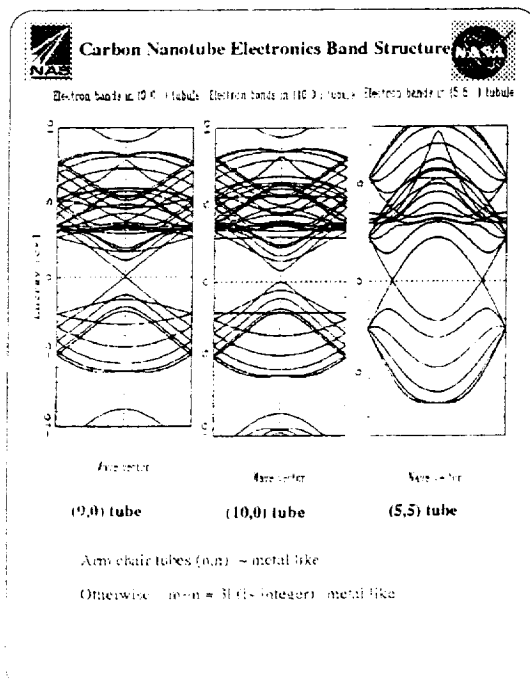
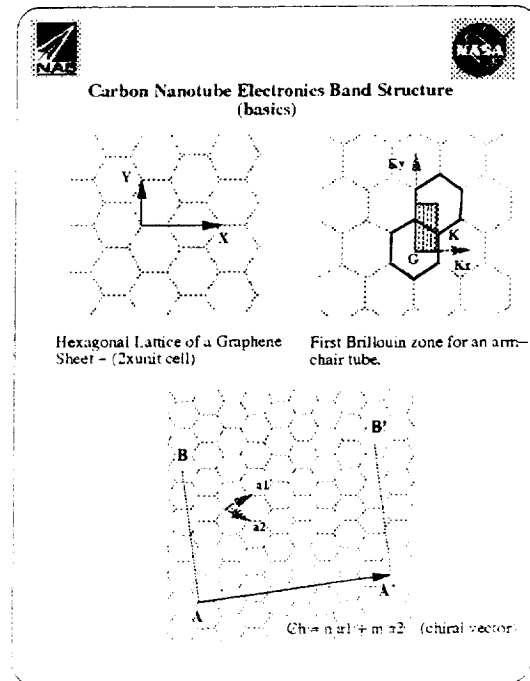
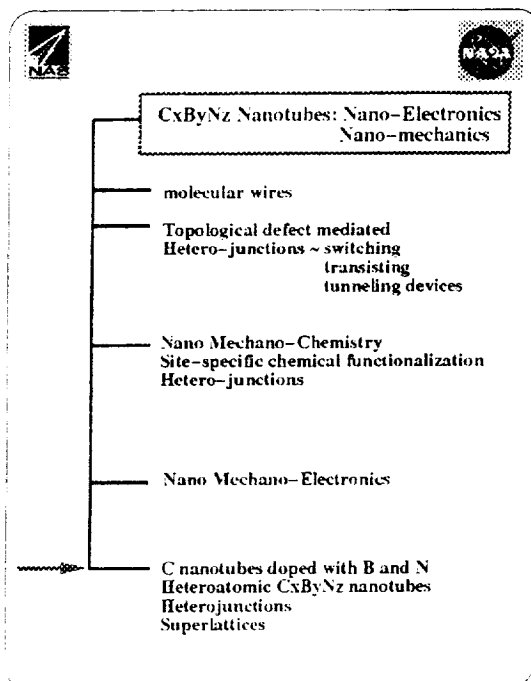
Experimental Status



Individual Single Wall Nanotubes as Quantum Wire

S. J. Tans et. al, *Nature* (April, 97)

- Nanotube Nanodevice – showing localized rectifying behavior in the *I/V* characteristics  
P. G. Collins et. al., *Science* (October, 97)
- *I/V* Characteristics and Electronic Structure (DOS) of structurally nanotubes.  
J.W.G. Wildoer et. al., *Nature* (January, 98)  
T. W. Odom et. al., *Nature* (January, 98)
- Single nanotube-molecule transistor at room temp.  
S. J. Tans et. al. (*Nature*) (May, 98)
- Nanostructuring (cutting) of nanotubes with STM  
L. C. Venema et. al., *Appl. Phys. Lett.* (Nov, 97)



We studied the effect of capping the tubes and relaxing the junctions with a quantum GTBMD method.



## Topological Defect: Heterojunctions II



Figure 10: (a) Schematic of a 3-terminal T-junction of nanotubes. (b) Calculated local density of states (LDOS) for the T-junction. (c) Calculated LDOS for the T-junction.

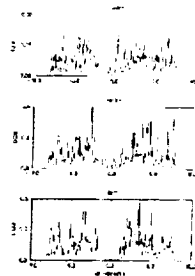
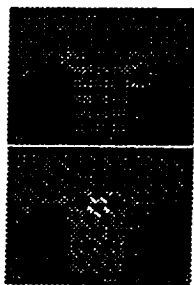


Figure 10: (a) Schematic of a 3-terminal T-junction of nanotubes. (b) Calculated local density of states (LDOS) for the T-junction. (c) Calculated LDOS for the T-junction.

LDOS of (10,0)-(9,0) "T-junction"

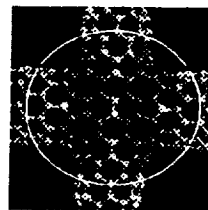
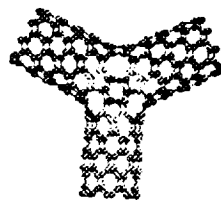
3-terminal "T-tunnel" Junctions of Nanotubes



## Topological Defects: Heterojunctions III



Pathways to Three-Dimensional Molecular "Networks"



Metal-Semiconductor-Metal

"Y" Tunnel Junction A four-terminal nanotube heterojunction

"It turns out that all of our proposed junctions satisfy - Generalized Euler's Rule about the global topology of connected networks"

- V. Crespi, Phys. Rev. Lett. (98)

These are "ideal" junctions and we don't know how to make these!

Some work is in progress to conceptualize and test "real" junctions.



## CxByNz Nanotubes and Junctions I



- Band gap engineering over a larger range should be possible:

BN  $\sim 5.5$  eV

$BC_2N$   $\sim 2.0$  eV

C  $\sim 0 - 1$  eV

$BC_3$   $\sim 0.5$  eV

- a variety of junctions, quantum dots and superlattices should be possible

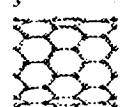
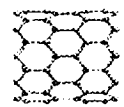
- should be more robust

- Example: Composite (10,0) nanotube

0.34 eV/atom

0.38 eV/atom

0.37 eV/atom



reconstruction due to polar BN bond



## CxByNz Nanotubes and Junctions II



- B doping of Carbon Nanotube

Random

Island ( $BC_3$ )

Superlattice ( $BC_3$ )



0.000

-0.013

-0.016 eV/atom

phase separation of doped and undoped regions is thermodynamically stable!

- BN/C Junctions



Interface Energy =  $2 \times \text{BN/C} - \text{BN} - \text{C}$   
Interface Energy = 0.33 eV/CB bond

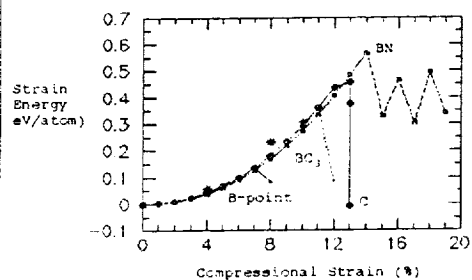
Stable interfaces should be possible!



### Cx By Nz Nanotubes and Junctions III



#### Nano-mechanics of Composite Nanotubes (8,0)



11%

15%



Structurally collapsed C nanotube

Structurally collapsed BN nanotube



#### Comments:

Proposed "new" nanotechnology materials and devices.

- multiple nanotube junctions and networks
- B, N doping, interfaces and tips

Tested feasibility of "new" concepts:

- Conformational strain driven mechanical - kinky - chemistry is certainly a new way to do site specific reactions on side-walls.
- feasibility of H storage in nanotube based material

Future possibilities are bright:

